TOSHIBA GaAs Linear Integrated Circuit GaAs Monolithic

TG2206F

RF SPDT Swith

Switch The Receive Filter for Mobile Communication

Switch The Diversity Antenna Switch The Local Signal

Features

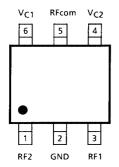
• Low insertion loss: Loss = 0.4dB (typ.)

• Hight isolation: ISL = 28dB (typ.)

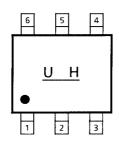
• Low voltage operation: $V_C = 0 \text{ V}/2.5 \text{ V}$

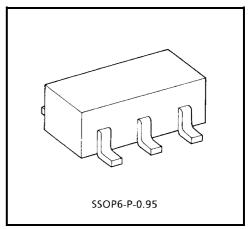
• Small package: SM6 package (2.9 × 1.6 × 1.1 mm)

Pin Assignment (top view)



Marking





Weight: 0.014 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Control voltage	V _{C1}	5	٧
Control voltage	V _{C2}	5	٧
Input power	Pi	1	W
Operating temperature range	T _{opr}	-40~85	°C
Storage temperature range	T _{stg}	-55~125	°C

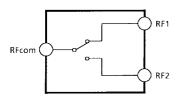
Caution

This device is electrostatic sensitivity. Please handle with caution.

Electrical Characteristics (f = 1 GHz, Ta = 25°C, Z_g = Z_l = 50 Ω)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Insertion loss	Loss (1)	1	V _{C1} = 2.5 V, V _{C2} = 0 V, P _i = 0dBmW		0.4	0.7	dB	
	L _{OSS} (2)	1	V _{C1} = 0 V, V _{C2} = 2.5 V, P _i = 0dBmW	ı	0.4	0.7	uБ	
Isolation	ISL (1)	1	$V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V},$ $P_i = 0 \text{dBmW}$	25	28	_	- dB	
	ISL (2)	1	V _{C1} = 0 V, V _{C2} = 2.5 V, P _i = 0dBmW	25	28	_	uБ	
Output power at 1dB gain compression	Po1dB	1	V _{C1} = 2.5 V, V _{C2} = 0 V or V _{C1} = 0 V, V _{C2} = 2.5 V	15	20	_	dBmW	
Control current	I _{C1}	_	V _{C1} = 0 V, V _{C2} = 3 V or	_	_	0.01	- mA	
	I _{C2}	_	$V_{C1} = 3 \text{ V}, V_{C2} = 0 \text{ V}$	_	_	0.01		
Switching time	t _{SW}	_	V _{C1} = 0 V, V _{C2} = 3 V or V _{C1} = 3 V, V _{C2} = 0 V		0.01	_	μs	

Block Diagram

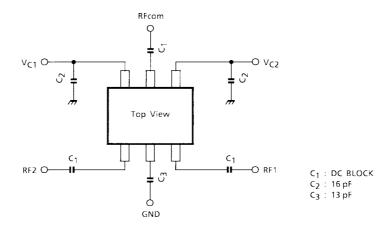


Switch Condition

Control Voltage	Switch Condition	
V _{C1} = 2.5 V V _{C2} = 0 V	RF _{Com} - RF1 OFF RF _{Com} - RF2 ON	
V _{C1} = 0 V	RF _{Com} - RF1 ON	
V _{C2} = 2.5 V	RF _{Com} - RF2 OFF	

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Test Circuit 1 (RF Test Circuit)



Please fix the value of each capacity for using frequency and circuit.

Notice

The circuits and measurements contained in this document are given only in the context of as examples of applications for these products.

Moreover, these example application circuits are not intended for mass production, since the high-frequency characteristics (the AC characteristics) of these devices will be affected by the external components which the customer uses, by the design of the circuit and by various other conditions.

It is the responsibility of the customer to design external circuits which correctly implement the intended application, and to check the characteristics of the design.

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TOSHIBA assume no responsibility for the integrity of customer circuit designs or applications.

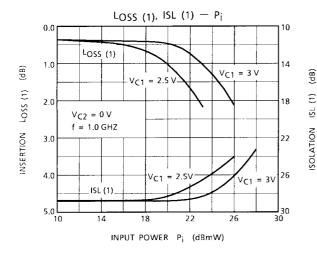
Recommend Capacity

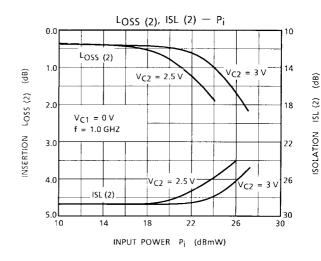
	85 MHz	0.8~1 GHz	1.6 GHz	2 GHz
C1	100 pF	100 pF	22 pF	9 pF
C2	100 pF	16 pF	10 pF	9 pF
C3	150 pF	13 pF	4 pF	3 pF

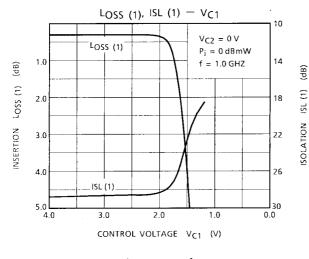
(9B)

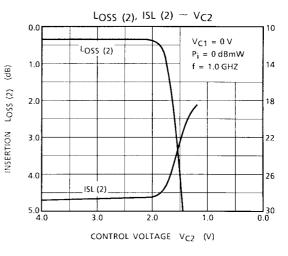
1SL (2)

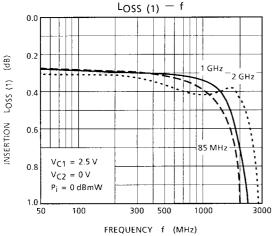
ISOLATION

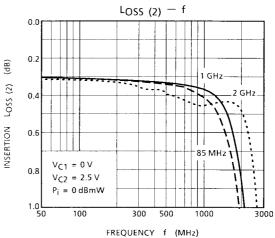






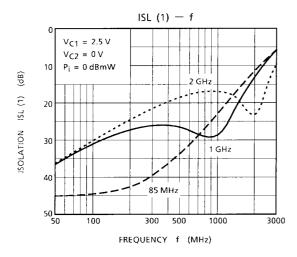




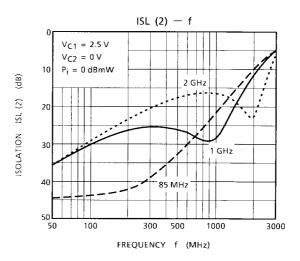


This curve shows the frequency characteristics when recommended capacitance for each frequency added.

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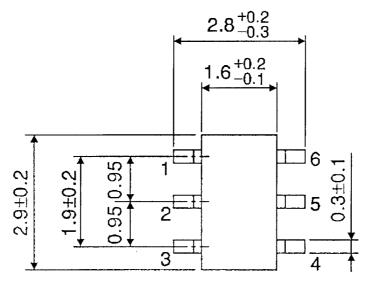
This curve shows the frequency characteristics when recommended capacitance for each frequency added.

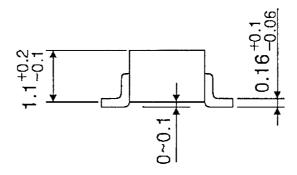


This curve shows the frequency characteristics when recommended capacitance for each frequency added.

Package Dimensions

SSOP6-P-0.95 Unit: mm





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Weight: 0.014 g (Typ.)

2002-07-31

RESTRICTIONS ON PRODUCT USE

020704EBC

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